

# **PN2907ATA Datasheet**



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DiGi Electronics Part Number PN2907ATA-DG

Manufacturer onsemi

Manufacturer Product Number PN2907ATA

Description TRANS PNP 60V 0.8A TO92-3

Detailed Description Bipolar (BJT) Transistor PNP 60 V 800 mA 200MHz 6

25 mW Through Hole TO-92-3



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# **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
PN2907ATA	onsemi
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
PNP	800 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
60 V	1.6V @ 50mA, 500mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
20nA (ICBO)	100 @ 150mA, 10V
Power - Max:	Frequency - Transition:
625 mW	200MHz
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Through Hole
Package / Case:	Supplier Device Package:
TO-226-3, TO-92-3 (TO-226AA) Formed Leads	TO-92-3
Base Product Number:	
PN2907	

# **Environmental & Export classification**

8541.21.0075

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	Not Applicable
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	

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# PN2907A / MMBT2907A / PZT2907A 60 V PNP General-Purpose Transistor

### **Features**

- High DC Current Gain (h<sub>FF</sub>) Range: 100 ~ 300
- High-Current Gain Bandwidth Product (f<sub>T</sub>):
   200 MHz (Minimum)
- Maximum Turn-On Time (t<sub>on</sub>): 45 ns
- Maximum Turn-Off Time (toff): 100 ns
- Ultra-Small Surface-Mount Package: SOT-223 (PZT2907A)

# **Description**

The PN2907A, MMBT2907A, and PZT2907A are 60 V PNP bipolar transistors designed for use as a general-purpose amplifier or switch in applications that require up to 500 mA. Offered in an ultra-small surface-mount package (SOT-223), the PZT2907A is ideal for space-constrained systems. The NPN complementary types are the PN2222A, MMBT2222A, and PZT2222A; respectively.

# **Applications**

- · General-Purpose Amplifier
- Switch



# **Ordering Information**

Part Number	Top Mark	Package	Packing Method
PN2907ABU	2907A	TO-92 3L	Bulk
PN2907ATF	2907A	TO-92 3L	Tape and Reel
PN2907ATFR	2907A	TO-92 3L	Tape and Reel
PN2907ATA	2907A	TO-92 3L	Ammo
PN2907ATAR	2907A	TO-92 3L	Ammo
MMBT2907A	2F	SOT-23 3L	Tape and Reel
MMBT2907A-D87Z	2F	SOT-23 3L	Tape and Reel
PZT2907A	2907A	SOT-223 4L	Tape and Reel

# **Absolute Maximum Ratings**(1),(2)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_A = 25^{\circ}C$  unless otherwise noted.

Symbol	Parameter	Value	Unit
$V_{CEO}$	Collector-Emitter Voltage	-60	V
$V_{CBO}$	Collector-Base Voltage	-60	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5.0	V
I <sub>C</sub>	Collector Current - Continuous	-800	mA
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

### Notes:

- 1. These ratings are based on a maximum junction temperature of 150°C.
- 2. These are steady-state limits. ON Semiconductor should be consulted on applications involving pulsed or lowduty cycle operations.

# **Thermal Characteristics**

Values are at  $T_A$  = 25°C unless otherwise noted.

Symbol	Parameter	Max.			
		PN2907A <sup>(4)</sup>	MMBT2907A <sup>(3)</sup>	PZT2907A <sup>(4)</sup>	Unit
D	Total Device Dissipation	625	350	1000	mW
P <sub>D</sub>	Derate Above 25°C	5.0	2.8	8.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3			°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	125	°C/W

### Notes:

- 3. Device is mounted on FR-4 PCB 1.6 inch X 1.6 inch X 0.06 inch.
- 4. PCB size: FR-4 76 x 114 x 1.57 mm<sup>3</sup> (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

# **Electrical Characteristics**

Values are at  $T_A = 25^{\circ}C$  unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Max.	Unit
Off Charac	cteristics			•	
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage <sup>(5)</sup>	I <sub>C</sub> = -10 mA, I <sub>B</sub> = 0	-60		V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = -10 μA, I <sub>E</sub> = 0	-60		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = -10 \mu A, I_C = 0$	-5.0		V
I <sub>BL</sub>	Base Cut-Off Current	V <sub>CE</sub> = -30 V, V <sub>EB</sub> = -0.5 V		-50	nA
I <sub>CEX</sub>	Collector Cut-Off Current	V <sub>CE</sub> = -30 V, V <sub>EB</sub> = -0.5 V		-50	nA
ı	Collector Cut-Off Current	V <sub>CB</sub> = -50 V, I <sub>E</sub> = 0		-0.02	T
I <sub>CBO</sub>	Collector Cut-Oil Current	V <sub>CB</sub> = -50 V, I <sub>E</sub> = 0, T <sub>A</sub> = 150°C		-20	μΑ
On Charac	cteristics			•	
		I <sub>C</sub> = -0.1 mA, V <sub>CE</sub> = -10 V	75		
		I <sub>C</sub> = -1.0 mA, V <sub>CE</sub> = -10 V	100		
$h_{FE}$	DC Current Gain	I <sub>C</sub> = -10 mA, V <sub>CE</sub> = -10 V	100		
		$I_C = -150 \text{ mA}, V_{CE} = -10 V^{(5)}$	100	300	
	!	$I_C$ = -500 mA, $V_{CE}$ = -10 $V^{(5)}$	50		
\/ (aat)	Collector-Emitter Saturation Voltage <sup>(5)</sup>	I <sub>C</sub> = -150 mA, I <sub>B</sub> = -15 mA		-0.4	V
V <sub>CE</sub> (sat)		I <sub>C</sub> = -500 mA, I <sub>B</sub> = -50 mA		-1.6	
\/ (oot)	Dage Emitter Seturation Voltage	$I_C = -150 \text{ mA}, I_B = -15 \text{ mA}^{(5)}$	5 mA <sup>(5)</sup> -1.3		
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> = -500 mA, I <sub>B</sub> = -50 mA		-2.6	V
Small Sign	nal Characteristics			•	1
$f_{T}$	Current Gain - Bandwidth Product	I <sub>C</sub> = -50 mA, V <sub>CE</sub> = -20 V, f = 100 MHz	200		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = -10 V, I <sub>E</sub> = 0, f = 100 kHz		8.0	pF
C <sub>ib</sub>	Input Capacitance	$V_{EB} = -2.0 \text{ V}, I_{C} = 0, f = 100 \text{ kHz}$		30	pF
Switching	Characteristics			•	
t <sub>on</sub>	Turn-On Time			45	ns
t <sub>d</sub>	Delay Time	$V_{CC} = -30 \text{ V}, I_{C} = -150 \text{ mA},$ $I_{B1} = -15 \text{ mA}$		10	ns
t <sub>r</sub>	Rise Time	ואין דאין דאין		40	ns
t <sub>off</sub>	Turn-Off Time			100	ns
t <sub>s</sub>	Storage Time	$V_{CC} = -6.0 \text{ V, } I_{C} = -150 \text{ mA,}$ $I_{B1} = I_{B2} = -15\text{mA}$		80	ns
t <sub>f</sub>	Fall Time	1 181 - 182 10111/A		30	ns

5. Pulse test: pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2.0%.

# **Typical Performance Characteristics**

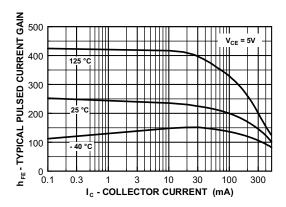


Figure 1. Typical Pulsed Current Gain vs. Collector Current

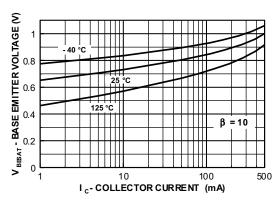


Figure 3. Base-Emitter Saturation Voltage vs. Collector Current

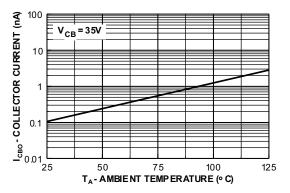


Figure 5. Collector Cut-Off Current vs.
Ambient Temperature

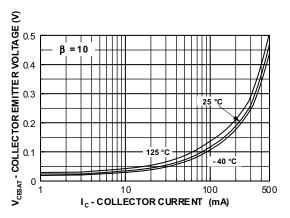


Figure 2. Collector-Emitter Saturation Voltage vs. Collector Current

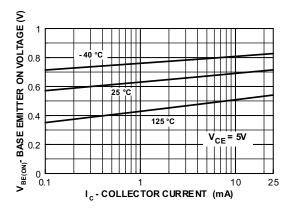


Figure 4. Base-Emitter On Voltage vs. Collector Current

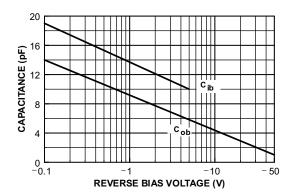


Figure 6. Input and Output Capacitance vs. Reverse Bias Voltage

# **Typical Performance Characteristics** (Continued)

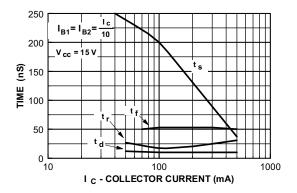


Figure 7. Switching Times vs. Collector Current

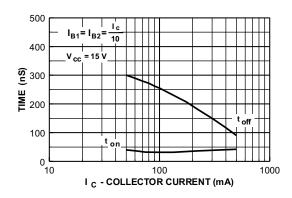


Figure 8. Turn-On and Turn-Off Times vs. Collector Current

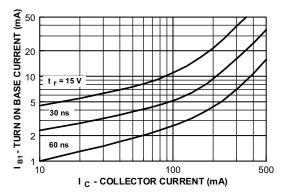


Figure 9. Rise Time vs. Collector and Turn-On Base Currents

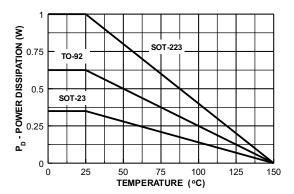


Figure 10. Power Dissipation vs. Ambient Temperature

# **Typical Performance Characteristics** (f = 1.0 kHz)

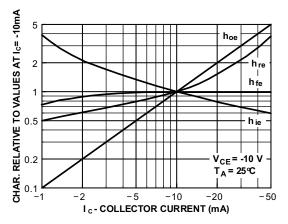


Figure 11. Common Emitter Characteristics

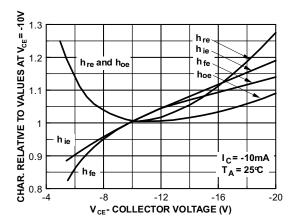


Figure 12. Common Emitter Characteristics

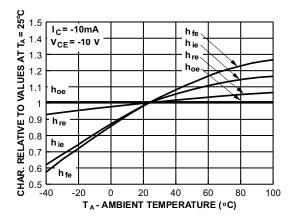
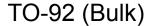


Figure 13. Common Emitter Characteristics

# **Physical Dimensions**



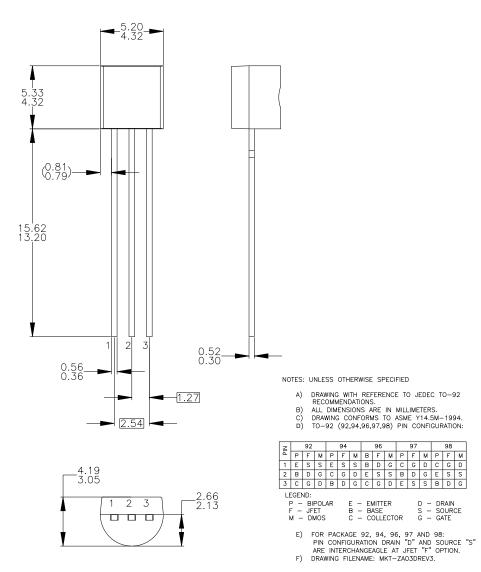
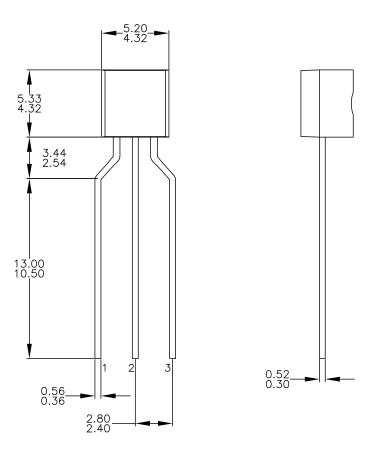


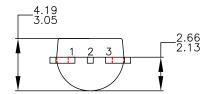
Figure 14. 3-LEAD, TO92, JEDEC TO-92 COMPLIANT STRAIGHT LEAD CONFIGURATION (OLD TO92AM3) (ACTIVE)

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# Physical Dimensions (Continued)

# TO-92 (Tape and Reel, Ammo)





NOTES: UNLESS OTHERWISE SPECIFIED

- DRAWING CONFORMS TO JEDEC MS-013, VARIATION AC.
  ALL DIMENSIONS ARE IN MILLIMETERS.
  DRAWING CONFORMS TO ASME Y14.5M-2009.
  DRAWING FILENAME: MKT-ZAO3FREV3.
- ON SEMICONDUCTOR

Figure 15. 3-LEAD, TO92, MOLDED 0.200 IN LINE SPACING LEAD FORM (J61Z OPTION) (ACTIVE)

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# Physical Dimensions (Continued) SOT-23 0.95 2.92±0.20 3 1.40 1.30<sup>+0.20</sup><sub>-0.15</sub> 2.20 2 0.60 0.37 (0.29) -0.95 ⊕ 0.20M A B 1.00 1.90 1.90 LAND PATTERN RECOMMENDATION 1.20 MAX SEE DETAIL A (0.93)0.10 ☐ 0.10 M C С 2.40±0.30 NOTES: UNLESS OTHERWISE SPECIFIED **GAGE PLANE** A) REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE H. B) ALL DIMENSIONS ARE IN MILLIMETERS. 0.23 0.08 C) DIMENSIONS ARE INCLUSIVE OF BURRS, 0.25 MOLD FLASH AND TIE BAR EXTRUSIONS. D) DIMENSIONING AND TOLERANCING PER ASME Y14.5M - 1994. 0.20 MIN E) DRAWING FILE NAME: MA03DREV10 **SEATING PLANE** (0.55)

Figure 16. 3-LEAD, SOT23, JEDEC TO-236, LOW PROFILE (ACTIVE)

**DETAIL A** 

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# Physical Dimensions (Continued)

# **SOT-223**

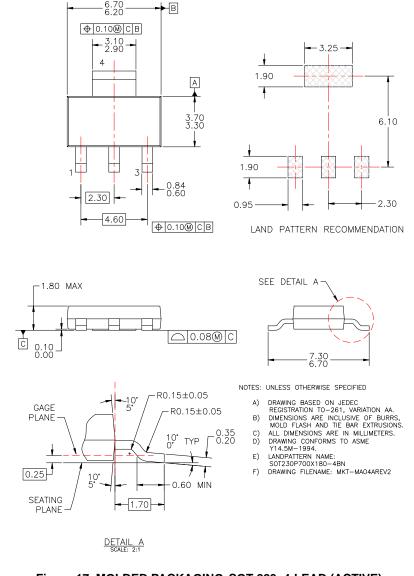


Figure 17. MOLDED PACKAGING, SOT-223, 4-LEAD (ACTIVE)

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